As a below named inventor, I hereby declare that:

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 My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought n the invention entitled:

SEMICONDUCTOR DEVICE HAVING THIN FILM FORMED BY ATOMIC LAYER DEPOSITION AND METHOD FOR FABRICATING THE SAME

	was amended on (i		l Application Number
hereby state that I have reviewed as mendment referred to above.	nd understand the contents of the above-identi	ified specification, including the claims	, as amended by any
acknowledge the duty to disclose in Regulations § 1.56.	nformation which is known by me to be mate	rial to patentability as defined in Title	37, Code of Federal
eventor's certificate, or § 365(a) of any		d at least one country other than the Unit	ed States, listed below
NUMBER .	COUNTRY	DAY/MONTH/YEAR FILED	PRIORITY CLAIMED
00-61548	Republic of Korea	19/October/2000	Yes
			. ,
			·
			
hereby claim the benefit under Title 3	5, United States Code § 119(e) of any United St	tates provisional application(s) listed belo	ow.
	APPLICATION NO.		
APPLIC	CATION NO.	FILING DATE	
APPLIC	CATION NO.		-

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s), or § 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose information which is known by me to be material to patentability as defined in Title 37, Code of Federal Regulations § 1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application:

	,	
APPLICATION SERIAL NO.	FILING DATE	STATUS: PATENTED, PENDING, ABANDONED
		· ·

I hereby appoint as my attorneys, with full powers of substitution and revocation, to prosecute this application and transact all business in the Patent and Trademark Office connected therewith: Eugene M. Lee, Reg. No. 32,039; Richard A. Sterba, Reg. No. 43,162.

Address all correspondence to Eugene M. Lee, The Law Offices of Eugene M. Lee, PLLC, 2111 Wilson Boulevard, Suite 1200, Arlington, Virginia 22201. Address all telephone communications to Eugene M. Lee at (703) 525-0978.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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